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ELECTRONICS

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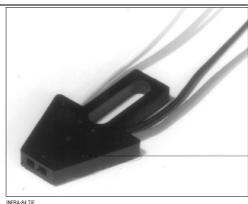
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Jameco Part Number 1861339

### **Reflective Sensor**

#### **FEATURES**

- Choice of phototransistor or photodarlington output
- Low profile package
- · Hermetic style emitter and detector
- · Focused for maximum response
- 24.0 in.(610 mm) min. 26 AWG Teflon insulated lead wires



#### DESCRIPTION

The HOA1406 series consists of an infrared emitting diode facing an NPN silicon phototransistor (HOA1406-001) or photodarlington (HOA1406-003) encased side- by- side on converging optical axes, in a black thermoplastic housing. The detector responds to radiation from the IRED only when a reflective object passes within its field of view. This low profile sensor is ideally suited for applications where space is limited, or stacking of sensors is required. The HOA1406 series employs hermetically sealed metal can packaged components. For additional component information see SE2460, SD2440, SD2410.

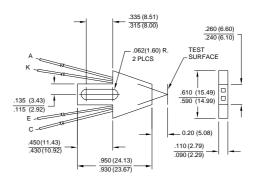
Housing material is polycarbonate. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

Wire color code and functions are:

IRFD anode - red IRED cathode - black Collector - white Emitter - green

### **OUTLINE DIMENSIONS** in inches (mm)

3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)



DIM\_072.ds4



### **Reflective Sensor**

#### ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	I <sub>F</sub> =20 mA
Reverse Leakage Current	I <sub>R</sub>			10	μΑ	V <sub>R</sub> =3 V
DETECTOR Collector-Emitter Breakdown Voltage HOA1406-001 HOA1406-003	V <sub>(BR)</sub> CEO	30 15			<b>V</b>	Ic=100 μA
Emitter-Collector Breakdown Voltage	V <sub>(BR)ECO</sub>	5.0			V	I <sub>E</sub> =100 μA
Collector Dark Current HOA 1406-001 HOA1406-003	Iceo			100 250	nA	V <sub>CE</sub> =10 V, I <sub>F</sub> =0
COUPLED CHARACTERISTICS On-State Collector Current HOA1406-001 HOA1406-003	Ic(on)	25 2.0			μΑ mA	VcE=5 V I <sub>F</sub> =40 mA
Crosstalk (2)	lcx			2.0	μΑ	V <sub>CE</sub> =5 V, I <sub>F</sub> =40 mA
Collector-Emitter Saturation Voltage HOA1406-001 HOA1406-003	VCE(SAT)			0.4 1.1	V	I <sub>F</sub> =40 mA <sup>(1)</sup> I <sub>C</sub> =10 µA I <sub>C</sub> =1 mA
Rise And Fall Time HOA1406-001 HOA1406-003	t <sub>r</sub> , t <sub>f</sub>		15 75		μs	$V_{CC}$ =5 V, $I_{C}$ =1 mA $R_{L}$ =1000 $\Omega$ $R_{L}$ =100 $\Omega$

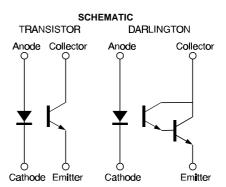
#### **ABSOLUTE MAXIMUM RATINGS**

(25°C Free-Air Temperature unless otherwise noted) Operating Temperature Range -40°C to 100°C Storage Temperature Range -40°C to 100°C IR EMITTER

80 mW (1) Power Dissipation Reverse Voltage 3 V Continuous Forward Current 50 mA TRANS.

**DETECTOR** Collector-Emitter Voltage 30 V

15 V 5 V Emitter-Collector Voltage 5 V Power Dissipation 75 mW (2) 75 mW (2) Collector DC Current 30 mA 30 mA



Honeywell reserves the right to make changes in order to improve design and supply the best products possible. Honeywell

DARLINGTON

Notes
1. Test surface is a Eastman Kodak neutral white card with 90% diffuse reflectance located 0.20 in. (5.0 mm) from the front surface of the device.

2. Crosstalk (lcx) is the collector current measured with current to emitter and no reflecting surface.

### **Reflective Sensor**

Fig. 1 IRED Forward Bias Characteristics

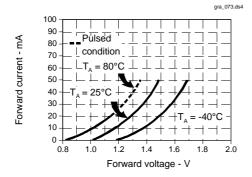


Fig. 2 Non-Saturated Switching Time vs Load Resistance gra\_079.ds4

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100

Phototransistor

Load resistance - Ohms

1000

10000

Fig. 3 Dark Current vs

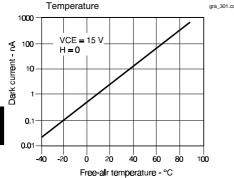


Fig. 4 Collector Current vs

10

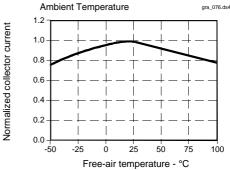


Fig. 5 Collector Current vs

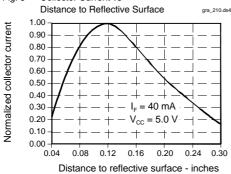
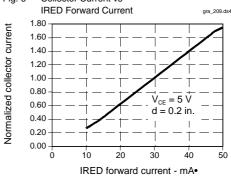


Fig. 6 Collector Current vs



All Performance Curves Show Typical Values

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